



# ESDALC6V1xxM6

## 4 and 5 line low capacitance TRANSIL™ array for ESD protection

### Main applications

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Computers
- Printers
- Communication systems
- Cellular phone handsets and accessories
- Video equipment

### Features

- 4 unidirectional TRANSIL diodes (ESDALC6V1M6)
- 5 unidirectional TRANSIL diodes (ESDALC6V1-5M6)
- Breakdown Voltage  $V_{BR} = 6.1 \text{ V min}$
- Low diode capacitance (12 pF typ at 0V)
- Low leakage current  $< 70 \text{ nA}$
- Very small PCB area:  $1.45 \text{ mm}^2$
- 500 microns pitch
- Leadfree package

### Description

The ESDALC6V1xxM6 is monolithic arrays designed to protect up to 4 or 5 lines against ESD transients.

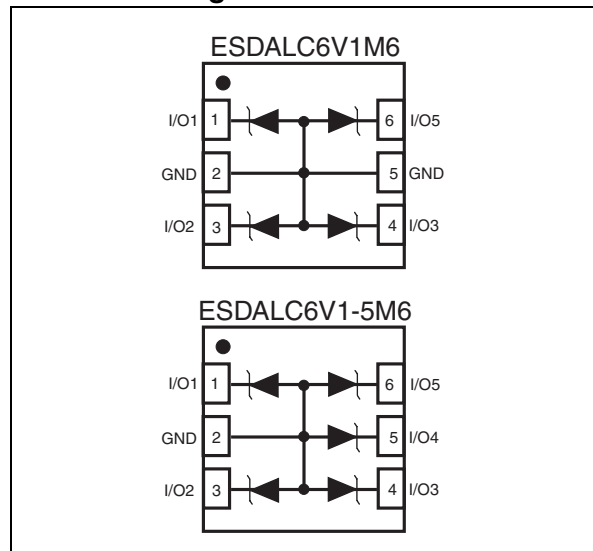
The device is ideal for applications where both reduced print circuit board space and power absorption capability are required.

### Benefits

- High ESD protection level
- High integration
- Suitable for high density boards



### Functional diagram



### Order Code

Part number	Marking
ESDALC6V1M6	G
ESDALC6V1-5M6	H

### Complies with the following standards:

#### IEC61000-4-2

- 15 kV (air discharge)
- 8 kV (contact discharge)

#### MIL STD 883E- Method 3015-7: class3

- 25 kV (human body model)

TM: TRANSIL is a trademark of STMicroelectronics

# 1 Characteristics

## 1.1 Absolute maximum ratings ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

Symbol	Parameter	Value	Unit
$V_{PP}$	ESD discharge – IEC61000-4-2 air discharge IEC61000-4-2 contact discharge	$\pm 15$ $\pm 8$	kV
$P_{PP}$	Peak pulse power dissipation (8/20 $\mu\text{s}$ ) <sup>(1)</sup>	$T_j$ initial = $T_{amb}$ 30	W
$I_{pp}$	Repetitive peak pulse current typical value (8/20 $\mu\text{s}$ )	3	A
$T_j$	Junction temperature	125	$^{\circ}\text{C}$
$T_{stg}$	Storage temperature range	-55 + 150	$^{\circ}\text{C}$
$T_L$	Maximum lead temperature for soldering during 10 s	260	$^{\circ}\text{C}$
$T_{OP}$	Operating temperature range	-40 + 125	$^{\circ}\text{C}$

1. For a surge greater than the maximum values, the diode will fail in short-circuit.

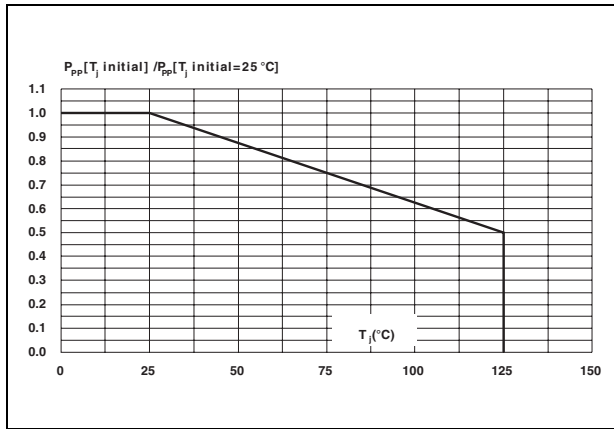
## 1.2 Electrical characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

Symbol	Parameter
$V_{RM}$	Stand-off voltage
$V_{BR}$	Breakdown voltage
$V_{CL}$	Clamping voltage
$I_{RM}$	Leakage current @ $V_{RM}$
$I_{PP}$	Peak pulse current
$\alpha T$	Voltage temperature coefficient
$V_F$	Forward voltage drop

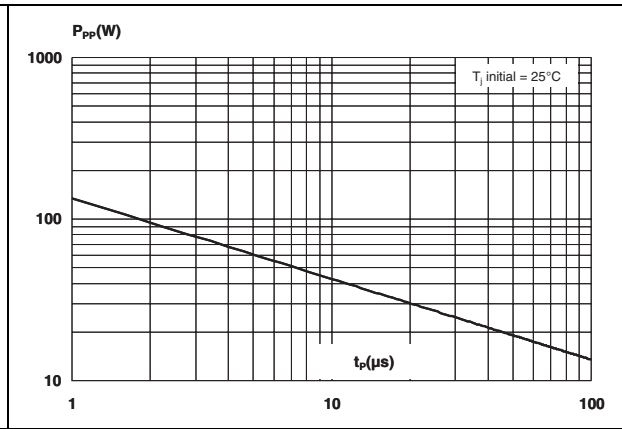
Parameter	Test Condition	Min	Typ	Max	Unit
$V_{BR}$	$I_R = 1\text{ mA}$	6.1		7.2	V
$I_{RM}$	$V_{RM} = 3\text{ V}$			70	nA
$V_F$	$I_F = 10\text{ mA}$			1	V
$R_d$			2		$\Omega$
$\alpha T^{(1)}$	$I_R = 1\text{ mA}$ ,			5	$10^{-4}/^{\circ}\text{C}$
C	$V_R = 0\text{ V DC}$ , $F = 1\text{ MHz}$ , $V_{osc} = 30\text{ mV}_{RMS}$		12		pF

1.  $\Delta V_{BR} = \alpha T * (T_{amb} - 25\text{ }^{\circ}\text{C}) * V_{BR}(25\text{ }^{\circ}\text{C})$

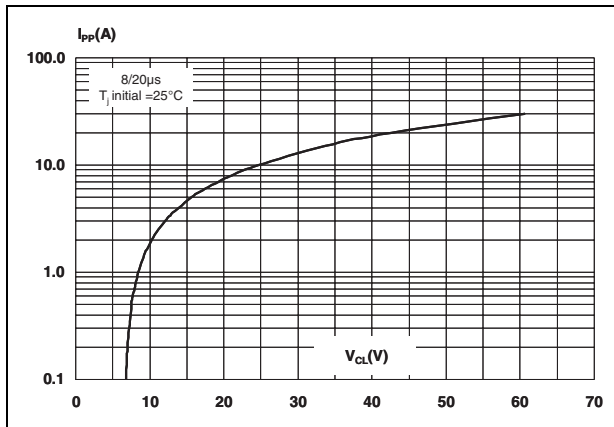
**Figure 1. Relative variation of peak pulse power versus initial junction temperature**



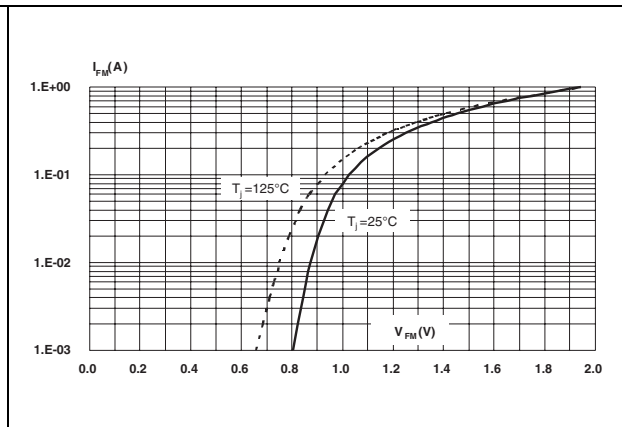
**Figure 2. Peak pulse power versus exponential pulse duration**



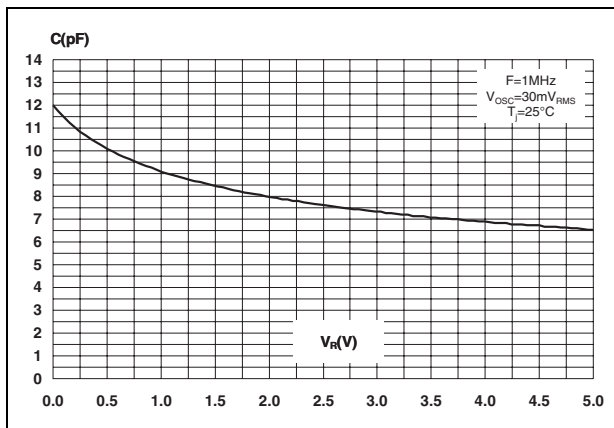
**Figure 3. Clamping voltage versus peak pulse current (typical values, rectangular waveform)**



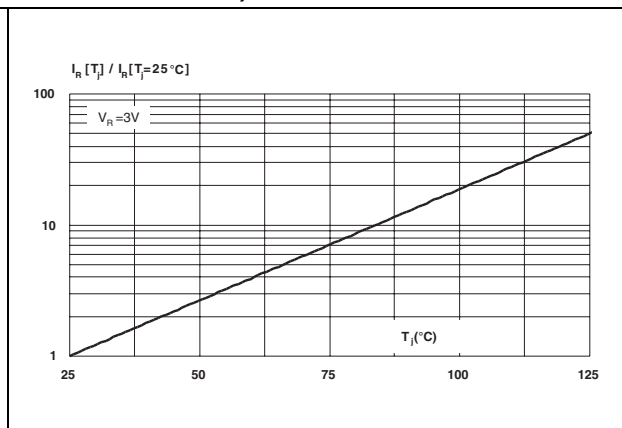
**Figure 4. Forward voltage drop versus peak forward current (typical values)**



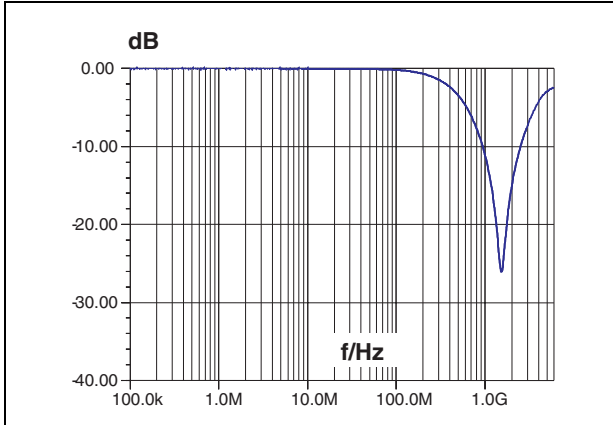
**Figure 5. Junction capacitance versus reverse voltage applied (typical values)**



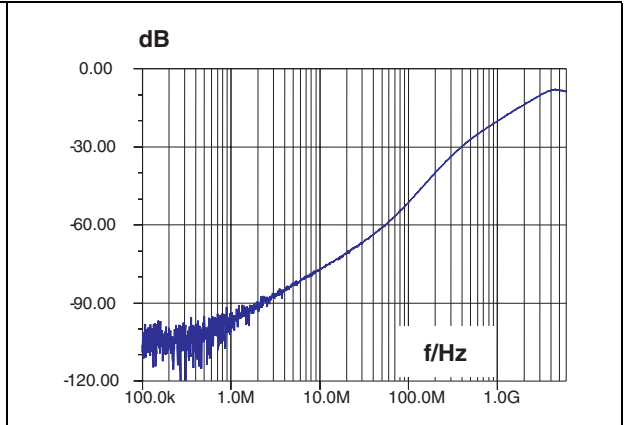
**Figure 6. Relative variation of leakage current versus junction temperature (typical values)**



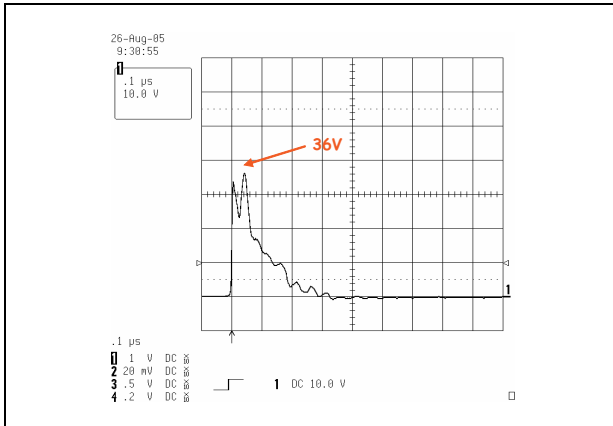
**Figure 7. S21 attenuation measurement results of each channel**



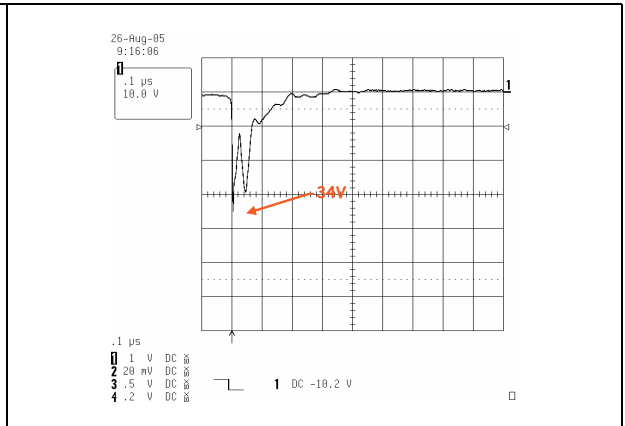
**Figure 8. Analog crosstalk measurements between channels**



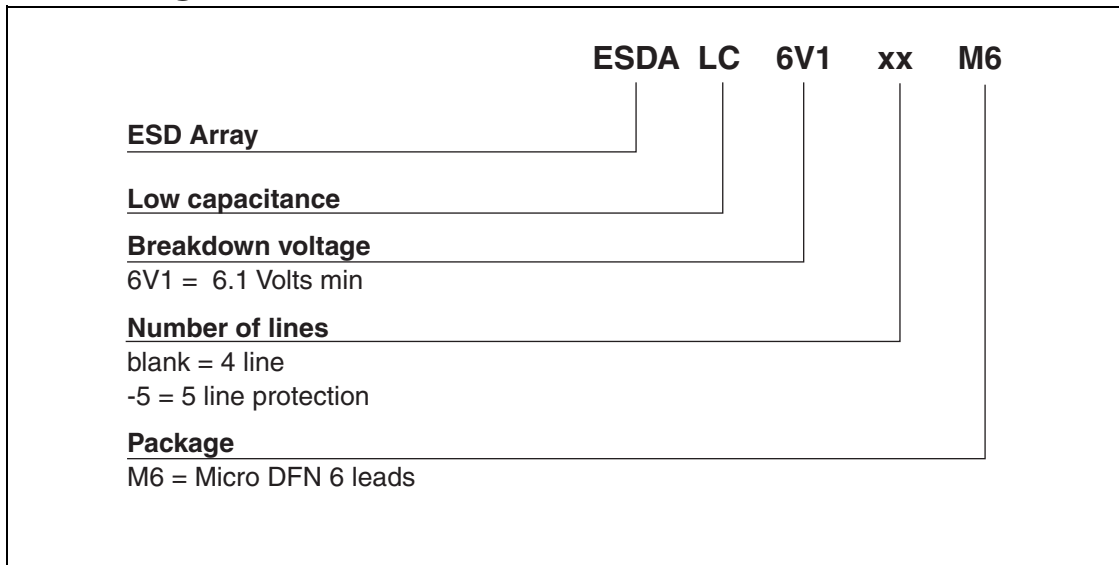
**Figure 9. ESD response to IEC6100-4-2 (+15 kV air discharge) on each channel**



**Figure 10. ESD response to IEC6100-4-2 (-15 kV air discharge) on each channel**



## 2 Ordering information scheme



## 3 Package information

Table 1. Mechanical data

REF	DIMENSIONS					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.50	0.55	0.60	0.20	0.22	0.24
A1	0.00	0.02	0.05	0.00	0.01	0.02
b	0.18	0.25	0.30	0.07	0.10	0.12
D		1.45			0.57	
E		1.00			0.39	
e		0.50			0.20	
k	0.20			0.08		
L	0.30	0.35	0.40	0.12	0.14	0.16

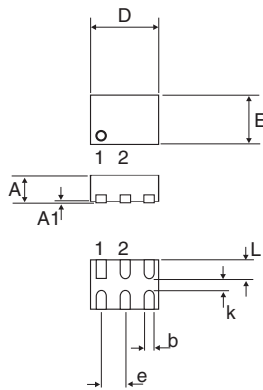


Figure 11. Footprint

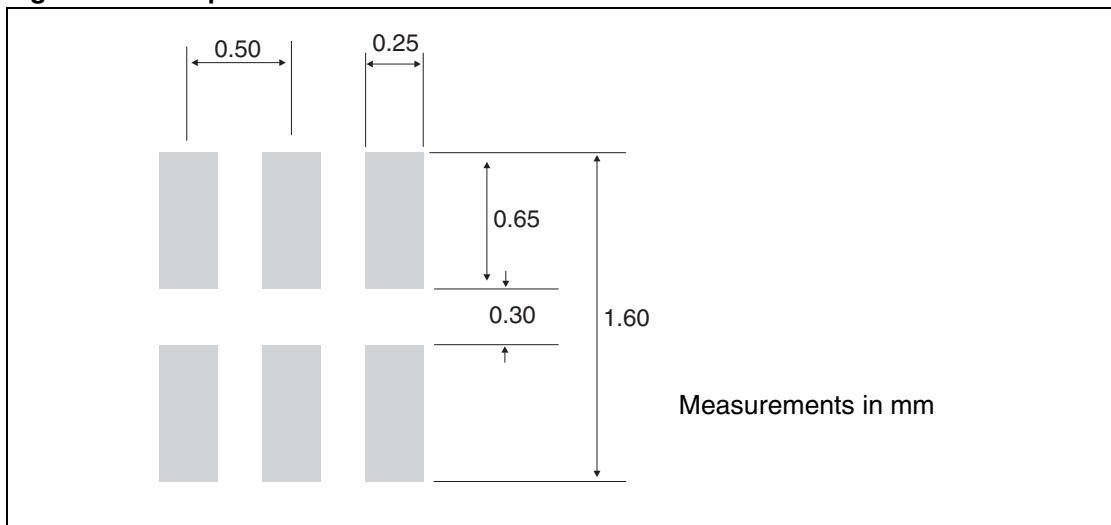
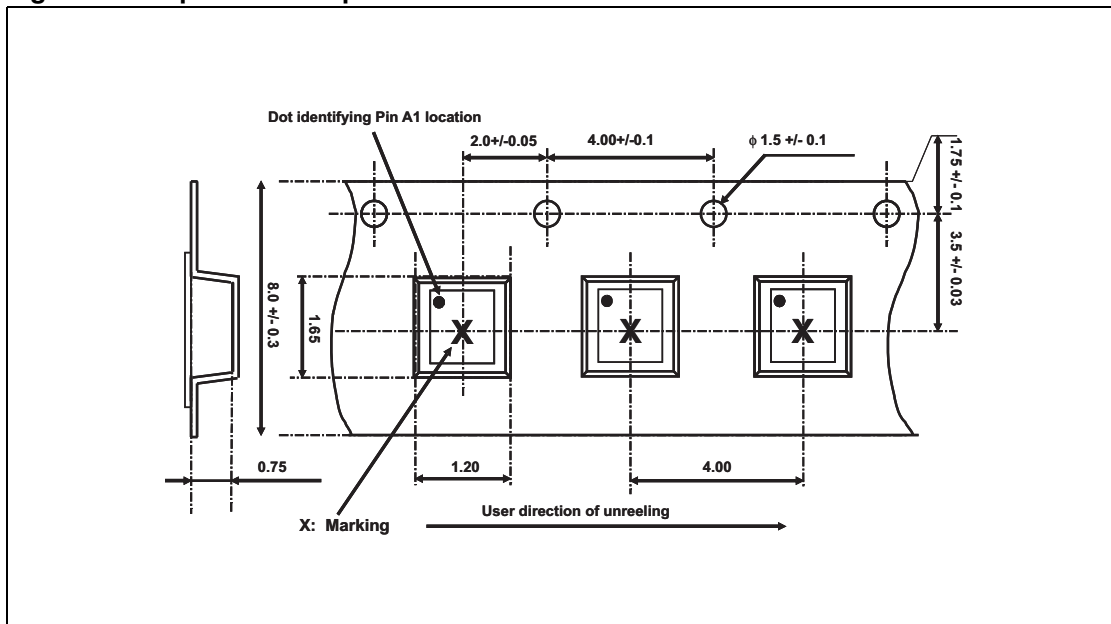


Figure 12. Tape and reel specification



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).

## 4 Ordering information

Part number	Marking	Package	Weight	Base qty	Delivery mode
ESDALC6V1M6	G	Micro DFN	2.2 mg	30,000	Tape and reel
ESDALC6V1-5M6	H	Micro DFN	2.2 mg	30,000	Tape and reel

## 5 Revision history

Date	Revision	Changes
19-Sep-2005	1	Initial release.

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics.  
All other names are the property of their respective owners

© 2005 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -  
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)